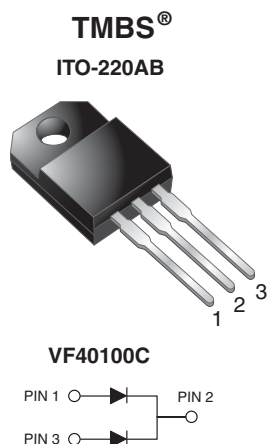


Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.38 \text{ V}$ at $I_F = 5 \text{ A}$



FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Solder dip 275 °C max., 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating
Base P/N-E3 - RoHS-compliant, commercial grade
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 20 A
V_{RRM}	100 V
I_{FSM}	250 A
V_F at $I_F = 20 \text{ A}$	0.61 V
$T_J \text{ max.}$	150 °C
Package	ITO-220AB
Circuit configuration	Common cathode

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VF40100C	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	100	V
Maximum average forward rectified current	$I_{F(AV)}$	40	A
(fig. 1)		20	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	250	A
Voltage rate of change (rated V_R)	dV/dt	10 000	V/ μ s
Isolation voltage from terminal to heatsink $t = 1 \text{ min}$	V_{AC}	1500	V
Operating junction and storage temperature range	T_J, T_{STG}	-40 to +150	°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.47	-	V
	I _F = 10 A			0.54	-	
	I _F = 20 A			0.67	0.73	
	I _F = 5 A	T _A = 125 °C		0.38	-	
	I _F = 10 A			0.45	-	
	I _F = 20 A			0.61	0.67	
Reverse current at rated V _R per diode	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	9	-	μA
		T _A = 125 °C		10	-	mA
	V _R = 100 V	T _A = 25 °C		-	1000	μA
		T _A = 125 °C		21	45	mA

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VF40100C	UNIT
Typical thermal resistance per diode	$R_{\theta JC}$	4.0	$^{\circ}\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VF40100C-M3/4W	1.75	4W	50/tube	Tube
ITO-220AB	VF40100C-E3/4W	1.75	4W	50/tube	Tube

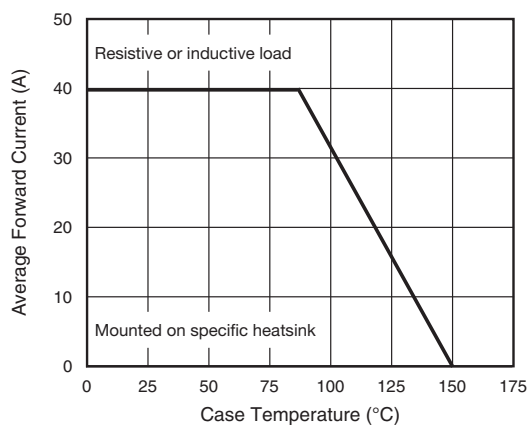
RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

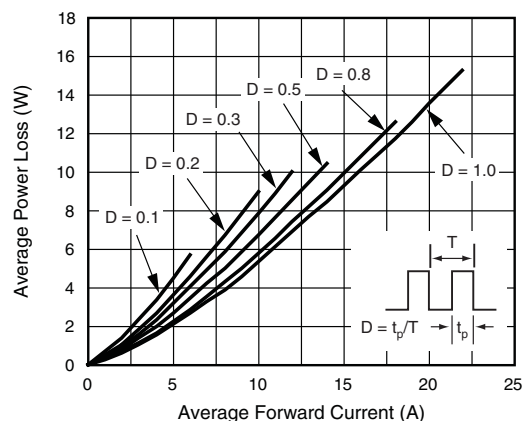


Fig. 2 - Forward Power Loss Characteristics Per Diode

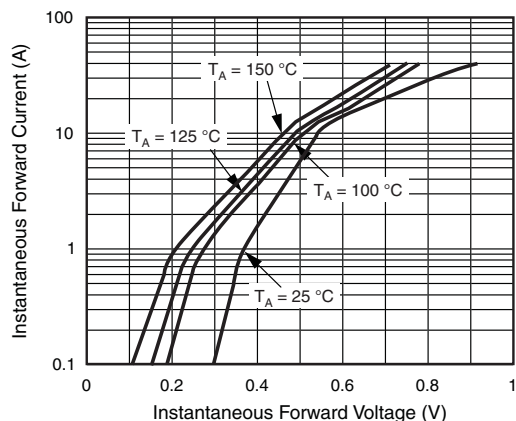


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

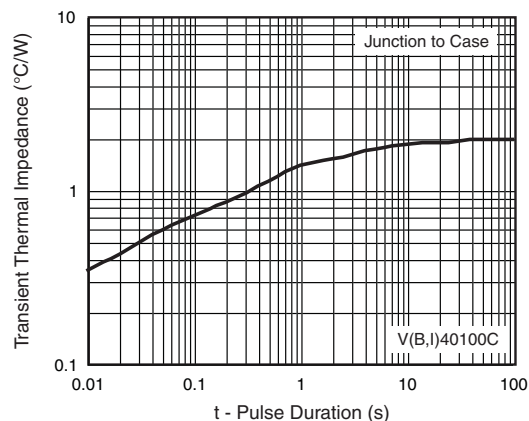


Fig. 6 - Typical Transient Thermal Impedance Per Diode

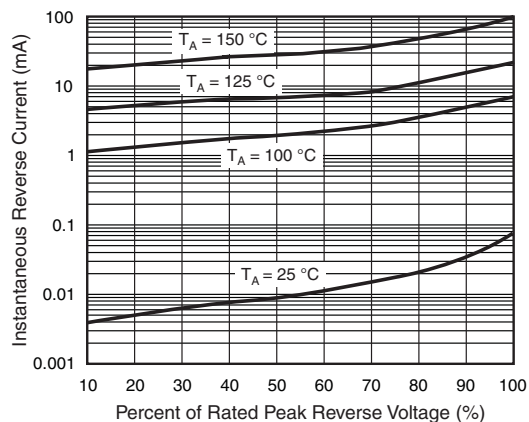


Fig. 4 - Typical Reverse Characteristics Per Diode

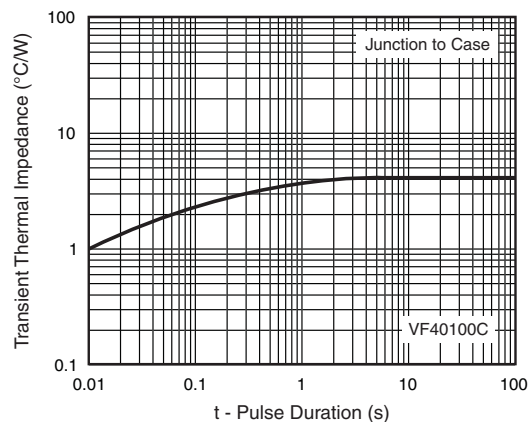


Fig. 7 - Typical Transient Thermal Impedance Per Diode

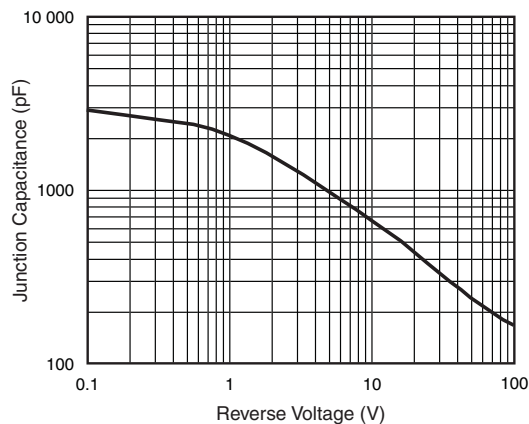
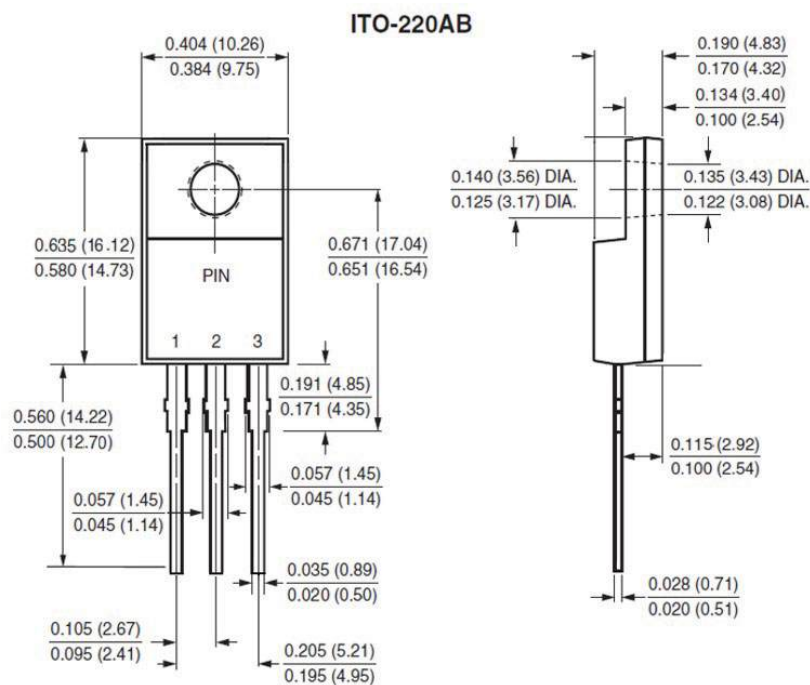


Fig. 5 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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